

3.0A Single-Phase GLass Passivated Bridge Rectifiers

Recifiter Reverse Voltage 50V to 1000V



Features

- Glass passivated junction
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- Suge overload ratings to 50 amperes peak
- Ideal for printed circuit board application
- ◆High temperature soldering guaranteed 265°C/10 seconds at 5 lbs(2.3kg)tension

Mechanical Data

Case:Molded plastic

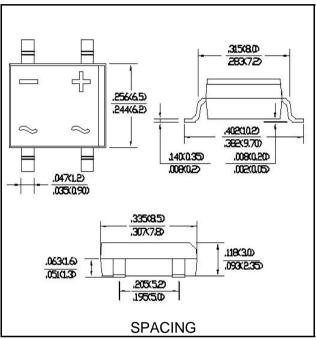
Terminals:Platde leads solderable per MIL-STD-750, Method 2026

Polarity:Polarity symbols molded or Marked on body

Mounting Position:Any

Weight: 0.01 ounce, 0.3 grams (approx)

<u>DBS</u>



Maximum Ratings & Thermal Characteristics

Rating at 25°C ambient temperature unless otherwise specified, Resistive or inductive load, 60HZ. For Capacitive load derate current by 20%

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Parameter	Symbol	DB301S	DB302S	DB303S	DB304S	DB305S	DB306S	DB307S	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified	IE(A\/\	20							Α
output current at TA=40°C	IF(AV)	IF(AV) 3.0							
Peak forward surge current single sine-wave	IFSM	85							А
superimposed on rated load (JEDEC Method)	IFSIVI								
Rating for fusing(t<8.3ms)	l ² t	10					A ² sec		
Typical thermal resistance per element(1)	ReJA	110						°C/w	
Typical thermal resistance per element(2)	Cj	25.0						PF	
Operating junction and stroage temperature	TJ,		FF40 : 4F0						°C
range	TSTG	-55to+150						$^{\circ}$	

Electrical Characteristics

Rating at 25 $^{\circ}$ C ambient temperature unless otherwise specified, Resistive or inductive load, 60 HZ.

For Capacitive load derate current by 20%

<u> </u>			
Parameter	Symbol	DB301S DB302S DB303S DB304S DB305S DB306S DB307S	unit
Maximum instantaneous forward voltage drop per leg at 3.0A	VF	1.1	V
Maximum DC reverse current at ratde TA=25°C DC blocking voltage per element TA=125°C	IR	10 500	UA

Notes:(1)Thermal resistance from Junction to Ambemt on P.C.board mounting.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 volts.





Rating and Characteristic Curves(TA=25°C Uniless otherwise noted)

